

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/538,878	06/14/2005	Masahiro Sakurada	124231	8834
25944	7590 06/15/2006		EXAMINER	
OLIFF & BERRIDGE, PLC P.O. BOX 19928			HITESHEW, FELISA CARLA	
ALEXANDRIA, VA 22320			ART UNIT	PAPER NUMBER
			1722	
		DATE MAILED: 06/15/2006		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)				
Office Action Summary		10/538,878	SAKURADA ET AL.				
		Examiner	Art Unit				
		Felisa C. Hiteshew	1722				
	The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
WHIC - Exter after - If NO - Failu Any r	ORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DASSIONS of time may be available under the provisions of 37 CFR 1.11 SIX (6) MONTHS from the mailing date of this communication. In period for reply is specified above, the maximum statutory period vere to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONEI	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).				
Status							
1)□	Responsive to communication(s) filed on						
	is action is FINAL . 2b)⊠ This action is non-final.						
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
,	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
4)🖂	4)⊠ Claim(s) <u>10-37</u> is/are pending in the application.						
	4a) Of the above claim(s) is/are withdrawn from consideration.						
	5) Claim(s) is/are allowed.						
6)⊠	☑ Claim(s) 10-37 is/are rejected.						
7)	Claim(s) is/are objected to.						
8)[Claim(s) are subject to restriction and/or	r election requirement.					
Applicati	on Papers						
9) 🗌 .	The specification is objected to by the Examine	г.					
10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).						
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority u	nder 35 U.S.C. § 119						
12)⊠ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).							
a)⊠ All b)☐ Some * c)☐ None of:							
	1.⊠ Certified copies of the priority documents have been received.						
	2. Certified copies of the priority documents have been received in Application No						
	3. Copies of the certified copies of the priority documents have been received in this National Stage						
application from the International Bureau (PCT Rule 17.2(a)).							
* See the attached detailed Office action for a list of the certified copies not received.							
	•						
Attachment	c(s)						
1) Notice	e of References Cited (PTO-892)	4) Interview Summary					
2) Motica 3) Inform	e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449 or PTO/SB/08)	Paper No(s)/Mail Da 5) Notice of Informal Pa	atent Application (PTO-152)				
Paper No(s)/Mail Date <u>see attached paper</u> . 6) Other:							

Application/Control Number: 10/538,878 Page 2

Art Unit: 1722

Priority

1. Receipt is acknowledged of papers submitted under 35 U.S.C. 119(a)-(d), which papers have been placed of record in the file.

Information Disclosure Statement

The PTOL 1449 has been received, reviewed and considered.

Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).
- 4. Claims 10-37 are rejected under 35 U.S.C. 103(a) as being unpatentable over Japanese Abstract 2000-351690.

Japan '690 teaches a Czochralski method of producing a silicon single crystal to form crystal in defect-free areas in good yield by changing the pulling velocity V and

Art Unit: 1722

temperature gradient G of a single crystal according to dopant concentration and keeping V/G value in the crystal interface within a prescribed rand in the radial direction of the crystal. Molten silicon L containing a dopant such as G, P, AI, Ga, As, In or Sb and additive elements such as a H, He, C, Ne, Ge, Kr, Sn, or Xe is housed in a crucible arranged in a heating chamber equipped with a heater and a heat insulating material and a silicon single crystal is pulled up through a seed crystal from the molten silicon. A pulling –up velocity V of the crystal S and /or a temperature gradient G on the crystal S side in crystal axial direction on the solid-liquid interface is changed according to the change of dopant concentration and V/G value is kept within a prescribed range. Thereby, an area generating ring-like oxidation induced stacking fault is made to vanish centering a wafer and a defect-free area without a dislocation cluster is formed in the whole radial direction.

The difference being that the Japanese '690 abstract does not exactly teach a value of F/G (mm²/*C x min) is a value or 2 or less, a melting point of silicon to 1400*C or an Al concentration being 2 x 10¹² atoms/cc or more. Japanese '690 does teach changing the pulling velocity V and temperature gradient in the crystal along the radial direction, which is similar to the F/G, as stated in the instant specification (see page 6, lines 22-27). Therefore, in the absence of unobvious result, it would have been obvious to one of ordinary skill in the art to modify and optimize the process and product parameter limitation in order to ensure proper orientation. The motivation being that a silicon single-crystal can be formed with a defect-free area while also providing a good yield.

Expected beneficial results are evidence of obviousness, just as unexpected beneficial results are evidence of unobviousness. In re Novak 16 USPQ 2d 2041 (Fed. Cir., BPAI 1989); In re Hoffman 194 USPQ 126 (CCPA 1977); In re Skoll 187 USPQ 481 (CCPA 1975); In re Skoner 186 USPQ 80 (CCPA 1975); In re Garshon 152 USPQ 602 (CCPA 1967).

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Felisa Hiteshew whose telephone number is (571) 272-1463. The examiner can normally be reached on Mondays through Thursday from 5:30 AM to 4:00 PM with Fridays off.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Yogendra Gupta, can be reached on (571) 272-1316. The fax phone number for the organization where this application or proceeding is assigned is (571) 273-1463.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system. see

http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866- 217-9197 (toll-free).

FELISA HITESHEW PRIMARY EXAMINER

AU 1708